# TOSHIBA

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

# 2SC3803

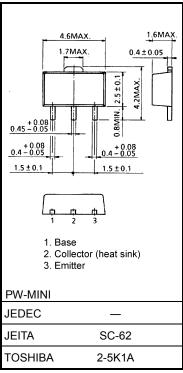
High Frequency Amplifier Applications Video Amplifier Applications High Speed Switching Applications

- High transition frequency:  $f_T = 200 \text{ MHz}$  (typ.)
- Low collector output capacitance:  $C_{ob} = 3.5 \text{ pF}$  (typ.)
- Complementary to 2SA1483

### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V <sub>CBO</sub>	60	V	
Collector-emitter voltage	V <sub>CEO</sub>	45	V	
Emitter-base voltage	V <sub>EBO</sub>	5	V	
Continuous collector current	Ι <sub>C</sub>	200	mA	
Continuous base current	Ι <sub>Β</sub>	50	mA	
Collector power dissipation	P <sub>C</sub>	500	mW	
	P <sub>C</sub>	1000		
	(Note 1)	1000		
Junction temperature	Тј	150	°C	
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C	

Note 1: Mounted on <u>a</u> ceramic substrate (250 mm<sup>2</sup> × 0.8 t)



Weight: 0.05 g (typ.)

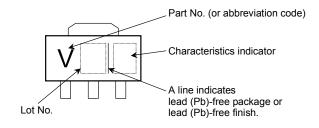
Unit: mm

## Electrical Characteristics (Ta = 25°C)

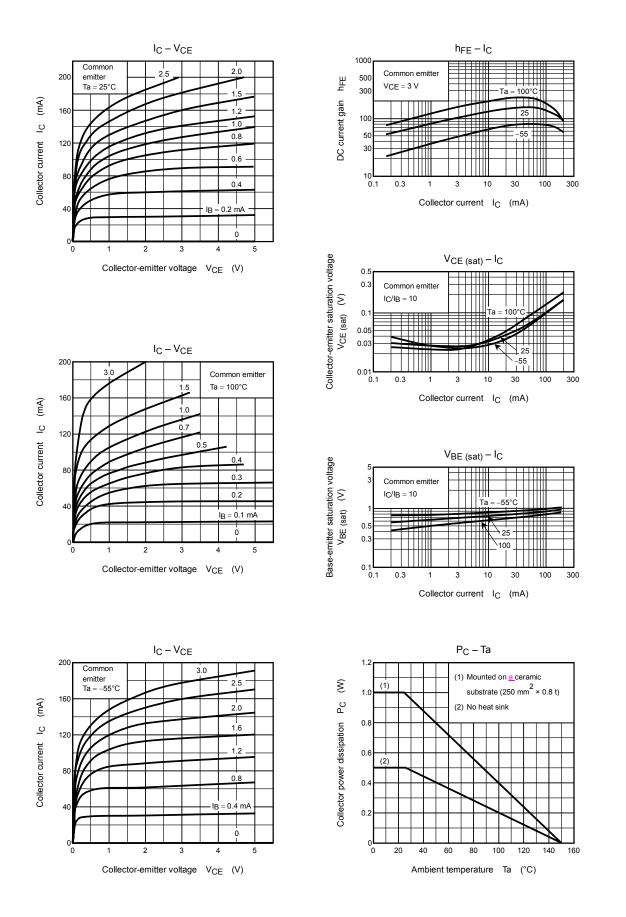
Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = 45 V, I <sub>E</sub> = 0	_	—	0.1	μA
Emitter cut-off current I <sub>EBO</sub>		V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	—	0.1	μA	
DC current gain (1		h <sub>FE (1)</sub> (Note 2)	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 10 mA	40	_	240	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 3 V, I <sub>C</sub> = 200 mA	20	_	_	
Collector-emitter	saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 100 mA, I <sub>B</sub> = 10 mA	_	_	0.3	V
Base-emitter satu	uration voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> = 100 mA, I <sub>B</sub> = 10 mA	_	_	1.0	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 10 mA	100	200	-	MHz
Input impedance (real part)		Re (h <sub>ie</sub> )	$V_{CE}$ = 10 V, I <sub>E</sub> = -10 mA, f = 200 MHz	_	_	120	Ω
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	3.5	5.0	pF
Switching time	Turn-on time	t <sub>on</sub>	OUTPUT INPUT 680 $\Omega$ 0 10 V $1 \mu S$ $V_{BB}$ U = -3 V DUTY CYCLE $\leq 2\%$	_	40	_	
	Storage time	t <sub>stg</sub>		_	250	_	ns
	Fall time	t <sub>f</sub>		_	30	_	

Note 2:  $h_{FE(1)}$  classification R: 40 to 80, O: 70 to 140, Y: 120 to 240

## Marking



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